

The RF Line NPN Silicon High-Frequency Transistor

Designed primarily for use in high-gain, low-noise small-signal amplifiers for operation up to 2.5 GHz. Also usable in applications requiring fast switching times.

- High Current-Gain — Bandwidth Product
- Low Noise Figure @ $f = 1.0$ GHz —
 $NF_{\text{(matched)}} = 1.8$ dB (Typ) (MRF9011LT1)
 $= 1.9$ dB (Typ) (MMBR901LT1, T3)
- High Power Gain —
 $G_{pe(\text{matched})} = 13.5$ dB (Typ) @ $f = 1.0$ GHz (MRF9011LT1)
 $= 12.0$ dB (Typ) @ $f = 1.0$ GHz (MMBR901LT1, T3)
- Guaranteed RF Parameters (MRF9011LT1)
- Surface Mounted SOT-23 & SOT-143 Offer Improved RF Performance
 Lower Package Parasitics
 High Gain
- Available in tape and reel packaging options:
 T1 suffix = 3,000 units per reel
 T3 suffix = 10,000 units per reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	15	Vdc
Collector-Base Voltage	V_{CBO}	25	Vdc
Emitter-Base Voltage	V_{EBO}	2.0	Vdc
Collector Current — Continuous	I_C	30	mAdc
Power Dissipation @ $T_C = 75^\circ\text{C}$ (1) MMBR901LT1, T3; MRF9011LT1	$P_{D(\text{max})}$	0.300	Watt
Derate above 25°C		4.00	mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 75^\circ\text{C}$ (1) Derate above 75°C MPS901	P_D	300	mW
Derate above 75°C		4.0	mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 75^\circ\text{C}$ (1) Derate above 75°C MRF901	P_D	0.375	Watt
Derate above 75°C		5.0	mW/ $^\circ\text{C}$
Storage Temperature Range All	T_{stg}	-55 to +150	$^\circ\text{C}$
Maximum Junction Temperature	$T_{J(\text{max})}$	150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Storage Temperature	T_{stg}	150	$^\circ\text{C}$
Thermal Resistance, Junction to Case MRF901 MRF9011LT1, MMBR901LT1, T3	$R_{\theta JC}$	200 250	$^\circ\text{C}/\text{W}$

DEVICE MARKING

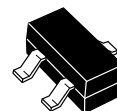
MRF9011LT1 = 01 MMBR901LT1, T3 = 7A

NOTE:

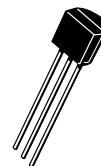
1. Case temperature measured on collector lead immediately adjacent to body of package.

**MMBR901LT1, T3
MPS901 MRF901
MRF9011LT1**

$I_C = 30$ mA
SURFACE MOUNTED
HIGH-FREQUENCY
TRANSISTOR
NPN SILICON



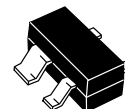
CASE 318-08, STYLE 6
SOT-23
LOW PROFILE, MMBR901LT1, T3



CASE 29-04, STYLE 2
TO-226AA (TO-92)
MPS901



CASE 317-01, STYLE 2
MRF901



CASE 318A-05, STYLE 1
SOT-143
LOW PROFILE, MRF9011LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 1.0\text{ mA}$, $I_B = 0$)	$V_{(BR)CEO}$	15	—	—	Vdc
Collector–Base Breakdown Voltage ($I_C = 0.1\text{ mA}$, $I_E = 0$)	$V_{(BR)CBO}$	25	—	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = 0.1\text{ mA}$, $I_C = 0$)	$V_{(BR)EBO}$	2.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = 15\text{ Vdc}$, $I_E = 0$)	I_{CBO}	—	—	50	nAdc

ON CHARACTERISTICS

DC Current Gain ($I_C = 5.0\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$)	MMBR901LT1, T3 MRF9011LT1, MPS901, MRF901	h_{FE}	50 30	— 80	200 200	—
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DYNAMIC CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = 15\text{ mA}$, $V_{CE} = 10\text{ Vdc}$, $f = 1.0\text{ GHz}$)	MRF9011LT1 MPS901, MRF901	f_T	— —	3.8 4.5	— —	GHz
Collector–Base Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	MRF9011LT1 MPS901 MRF901	C_{cb}	— — —	0.55 0.50 0.40	1.0 1.0 1.0	pF

FUNCTIONAL TESTS

Power Gain at Minimum Noise Figure ($V_{CE} = 10\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MRF9011LT1	G_{NFmin}	—	13.5	—	dB
Minimum Noise Figure (Figure 3) ($V_{CE} = 10\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MRF9011LT1	NF_{min}	—	1.8	—	dB
Insertion Gain in 50 Ω System ($V_{CE} = 10\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MRF9011LT1	$ S_{21} ^2$	9.0	10.2	—	dB
Minimum Noise Figure (Figure 3) ($V_{CE} = 6.0\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$) ($V_{CE} = 10\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MMBR901LT1, T3	NF_{min}	—	1.9	—	dB
Minimum Noise Figure (Figure 3) ($I_C = 5.0\text{ mA}$, $V_{CE} = 10\text{ Vdc}$, $f = 900\text{ MHz}$)	MPS901	NF_{min}	—	2.4	—	dB
Minimum Noise Figure (Figure 3) ($I_C = 5.0\text{ mA}$, $V_{CE} = 6.0\text{ Vdc}$, $f = 1.0\text{ GHz}$)	MRF901	NF_{min}	—	2.0	2.5	dB

SMALL–SIGNAL CHARACTERISTICS

Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MMBR901LT1	C_{obo}	—	—	1.0	pF
Common–Emitter Amplifier Gain ($V_{CC} = 6.0\text{ Vdc}$, $I_C = 5.0\text{ mA}$, $f = 1.0\text{ GHz}$)	MMBR901LT1	G_{pe}	—	12	—	dB

MRF9011LT1

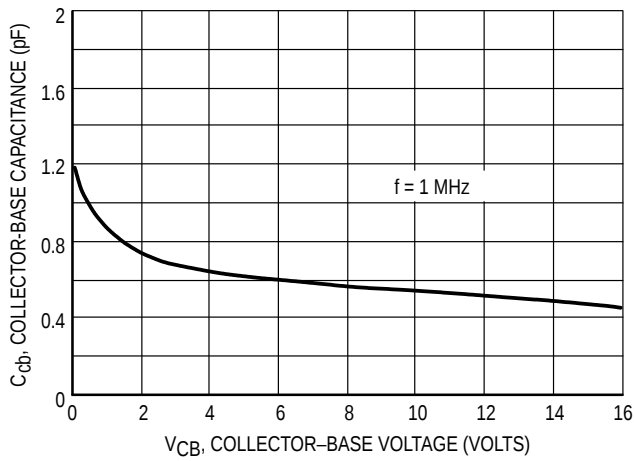


Figure 1. Collector-Base Capacitance versus Collector-Base Voltage

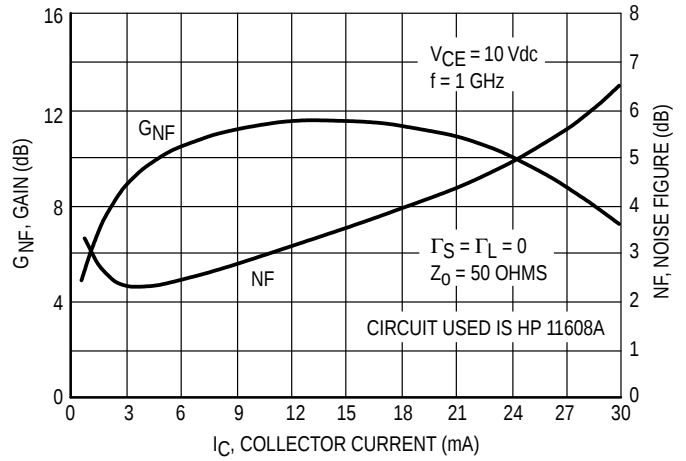


Figure 2. Gain and Noise Figure versus Collector Current

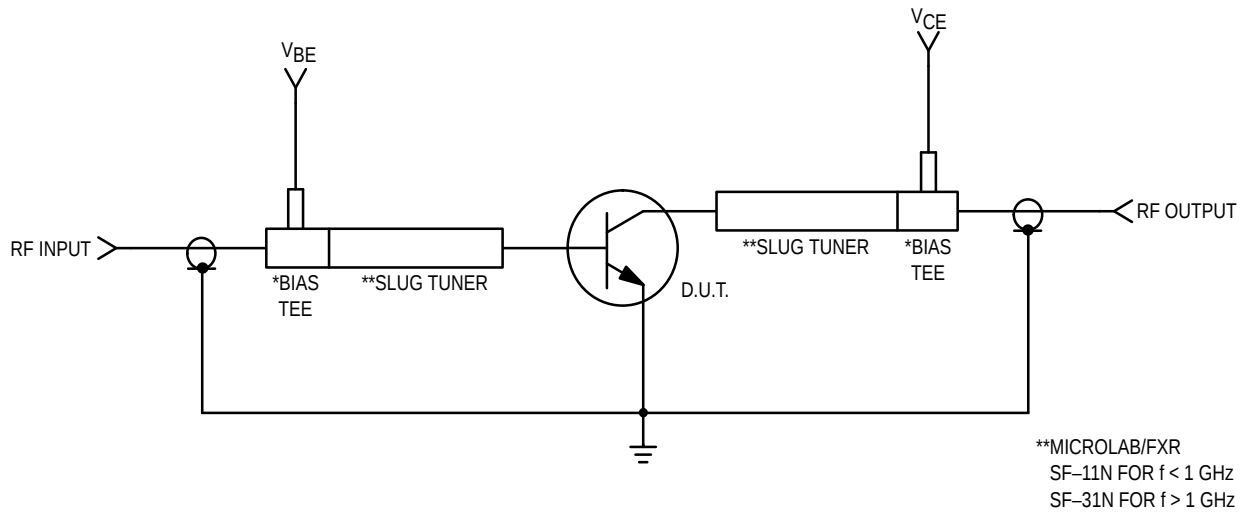


Figure 3. MRF9011LT1 Functional Circuit Schematic

MRF9011LT1

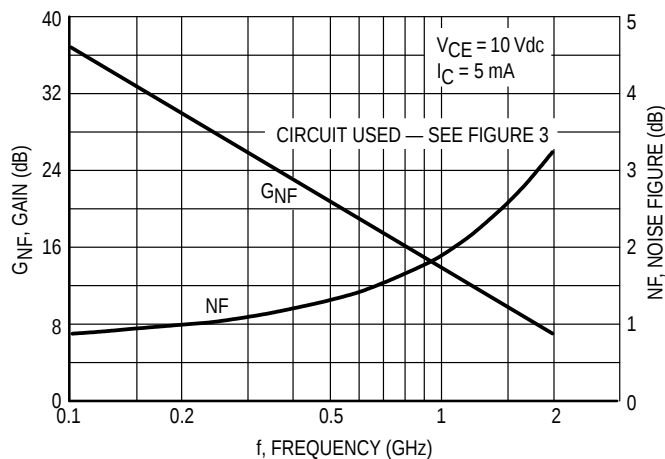


Figure 4. Gain and Noise Figure versus Frequency

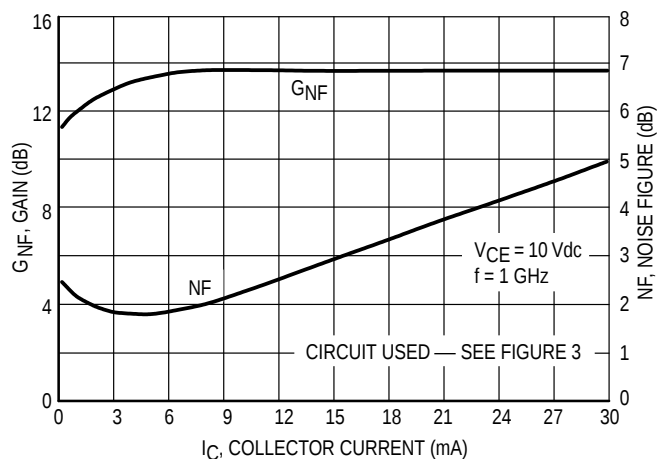


Figure 5. Gain and Noise Figure versus Collector Current

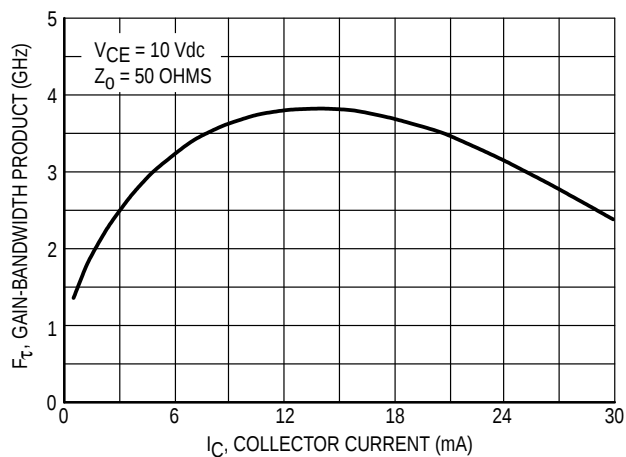


Figure 6. Gain-Bandwidth Product versus Collector Current

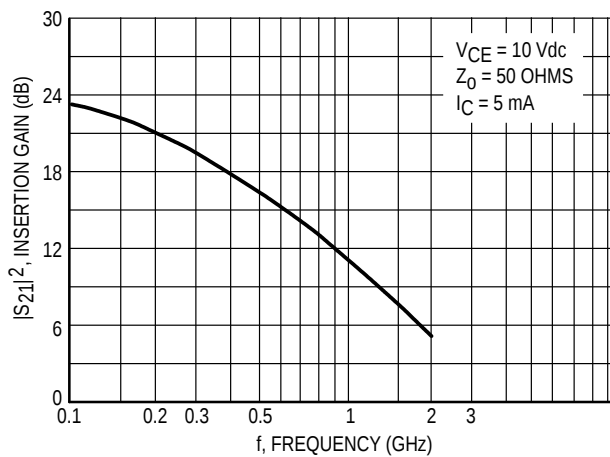


Figure 7. Insertion Gain versus Frequency

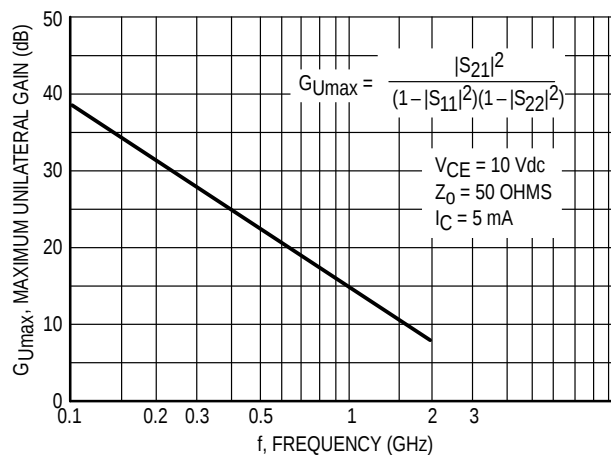


Figure 8. Maximum Unilateral Gain versus Frequency

V _{CE} (Vdc)	I _C (mA)	f (MHz)	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
			S ₁₁	∠ φ	S ₂₁	∠ φ	S ₁₂	∠ φ	S ₂₂	∠ φ
5.0	5.0	100	0.85	−41	13.64	153	0.03	65	0.93	−17
		200	0.78	−76	10.77	134	0.05	54	0.80	−29
		500	0.71	−131	6.10	102	0.08	35	0.55	−42
		1000	0.66	−169	3.22	77	0.08	33	0.45	−48
		2000	0.60	152	1.65	47	0.11	46	0.47	−63
	10	100	0.72	−59	20.01	145	0.03	62	0.87	−23
		200	0.70	−100	14.31	123	0.04	49	0.67	−36
		500	0.66	−150	7.03	94	0.06	38	0.44	−43
		1000	0.63	179	3.57	73	0.07	45	0.37	−46
		2000	0.58	147	1.79	46	0.11	57	0.41	−60
	15	100	0.65	−75	23.44	138	0.02	57	0.81	−27
		200	0.66	−118	15.56	116	0.04	46	0.59	−38
		500	0.65	−159	7.10	90	0.05	42	0.40	−40
		1000	0.63	174	3.57	71	0.06	52	0.35	−43
		2000	0.59	144	1.77	45	0.11	62	0.40	−58
	20	100	0.61	−89	24.32	133	0.02	51	0.77	−28
		200	0.66	−130	15.11	111	0.03	43	0.55	−35
		500	0.66	−166	6.68	88	0.04	46	0.41	−34
		1000	0.65	171	3.32	69	0.06	56	0.39	−39
		2000	0.61	143	1.65	43	0.10	65	0.44	−56
	30	100	0.63	−132	13.18	118	0.02	47	0.72	−15
		200	0.68	−157	7.07	104	0.02	44	0.66	−16
		500	0.69	−177	3.23	90	0.03	55	0.62	−24
		1000	0.70	165	1.78	71	0.05	65	0.59	−38
		2000	0.66	138	0.93	42	0.09	79	0.62	−62
10	5.0	100	0.85	−38	13.67	155	0.03	70	0.93	−14
		200	0.80	−71	10.97	136	0.05	56	0.83	−24
		500	0.70	−126	6.35	104	0.07	37	0.60	−35
		1000	0.65	−166	3.39	78	0.07	36	0.51	−40
		2000	0.58	154	1.74	48	0.10	50	0.54	−55
	10	100	0.75	−55	20.12	147	0.02	66	0.88	−19
		200	0.71	−94	14.60	125	0.04	50	0.72	−30
		500	0.65	−145	7.33	96	0.05	39	0.50	−35
		1000	0.62	−177	3.74	74	0.06	46	0.45	−38
		2000	0.57	149	1.88	47	0.10	60	0.49	−53
	15	100	0.68	−68	23.53	140	0.02	61	0.85	−22
		200	0.67	−110	15.90	119	0.03	49	0.65	−31
		500	0.64	−155	7.45	92	0.04	42	0.47	−32
		1000	0.62	177	3.74	71	0.06	53	0.44	−35
		2000	0.58	146	1.90	45	0.09	65	0.50	−51
	20	100	0.64	−79	24.77	135	0.02	56	0.81	−23
		200	0.64	−122	15.81	114	0.03	46	0.62	−29
		500	0.64	−161	7.10	89	0.04	46	0.48	−28
		1000	0.62	174	3.53	79	0.05	56	0.46	−33
		2000	0.59	145	1.75	44	0.09	68	0.53	−50
	30	100	0.61	−114	16.25	123	0.01	48	0.79	−15
		200	0.63	−147	9.10	107	0.02	49	0.71	−15
		500	0.65	−172	4.22	90	0.03	53	0.66	−22
		1000	0.66	168	2.27	71	0.05	63	0.63	−33
		2000	0.63	140	1.15	41	0.08	79	0.67	−53

Table 1. MRF9011LT1 Common Emitter S-Parameters

MPS901

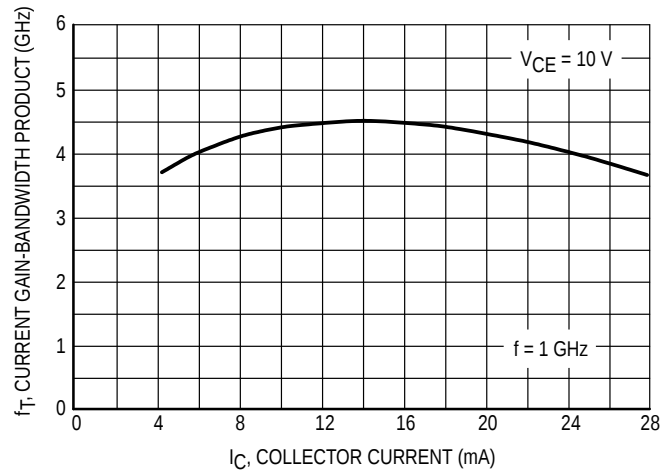


Figure 9. Current Gain–Bandwidth Product versus Collector Current

MPS901

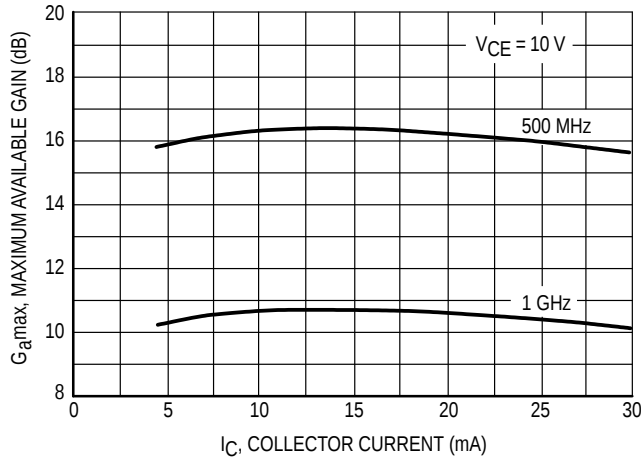


Figure 10. Maximum Available Gain versus Collector Current

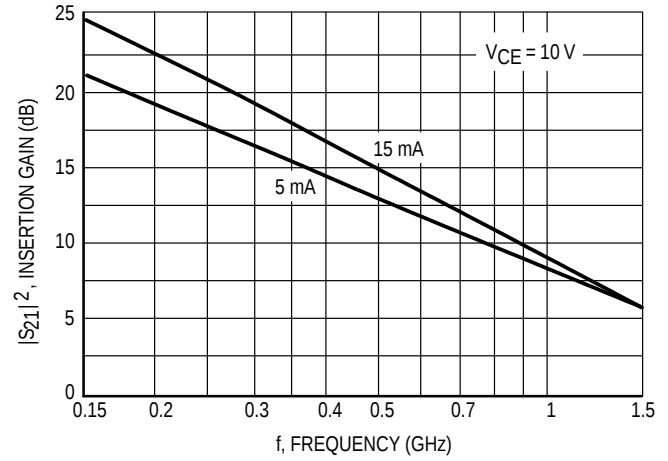


Figure 11. $|S_{21}|^2$ versus Frequency

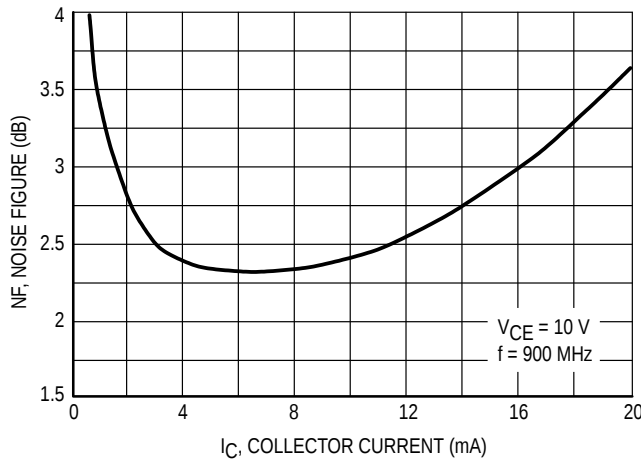


Figure 12. Noise Figure versus Collector Current

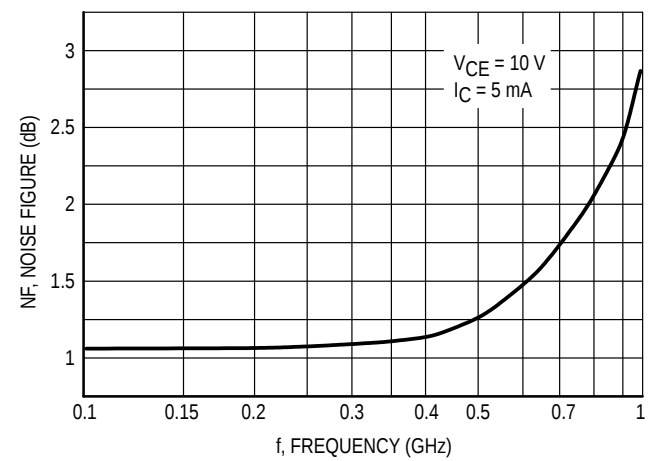


Figure 13. Noise Figure versus Frequency

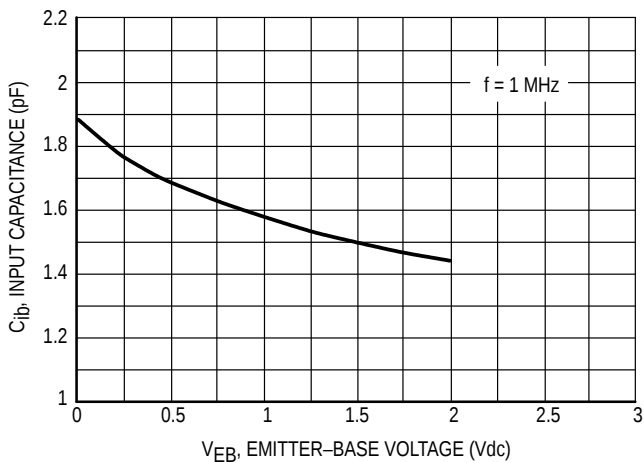


Figure 14. Input Capacitance versus Emitter-Base Voltage

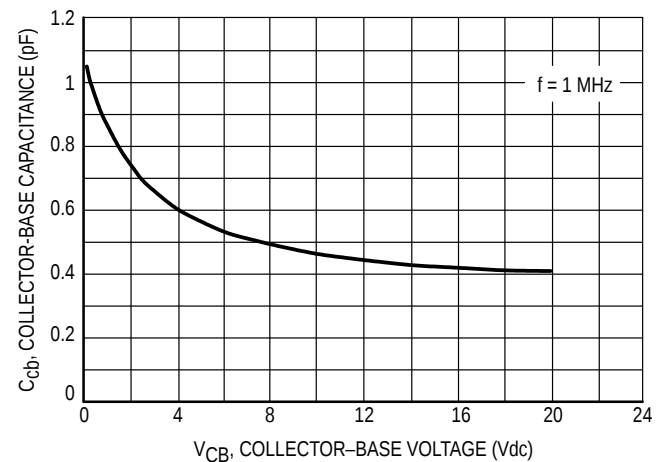


Figure 15. Collector-Base Capacitance versus Collector-Base Voltage

MPS901

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
5.0	5.0	100	0.76	-35	9.42	142	0.03	67	0.85	-18
		200	0.60	-63	7.98	122	0.05	58	0.70	-26
		500	0.28	-127	4.79	84	0.09	55	0.53	-35
		1000	0.27	148	2.71	50	0.15	51	0.42	-51
		1500	0.43	113	2.02	23	0.21	42	0.28	-79
	10	100	0.57	-51	14.80	131	0.03	65	0.75	-22
		200	0.36	-87	10.80	108	0.04	62	0.60	-26
		500	0.18	-151	5.23	77	0.08	62	0.48	-31
		1000	0.25	136	2.86	47	0.15	55	0.39	-48
		1500	0.42	109	2.12	22	0.22	42	0.25	-75
	15	100	0.42	-67	17.80	123	0.02	66	0.69	-22
		200	0.26	-105	11.50	101	0.04	66	0.56	-23
		500	0.17	-169	5.27	74	0.08	66	0.47	-28
		1000	0.26	131	2.86	46	0.15	57	0.39	-47
		1500	0.43	108	2.12	21	0.22	44	0.25	-73
	20	100	0.33	-82	18.66	117	0.02	67	0.66	-21
		200	0.22	-120	11.54	98	0.03	68	0.55	-21
		500	0.17	-171	5.16	72	0.08	67	0.48	-27
		1000	0.28	129	2.80	45	0.15	58	0.40	-45
		1500	0.45	107	2.07	19	0.22	45	0.27	-71
	25	100	0.28	-103	18.11	113	0.02	68	0.64	-20
		200	0.22	-138	11.03	95	0.03	70	0.55	-19
		500	0.20	169	4.94	71	0.08	68	0.50	-25
		1000	0.32	128	2.68	43	0.15	60	0.42	-44
		1500	0.49	106	1.98	17	0.22	47	0.30	-71
	30	100	0.31	-127	16.10	109	0.02	67	0.64	-16
		200	0.28	-156	9.69	93	0.03	70	0.57	-16
		500	0.28	160	4.32	69	0.07	70	0.53	-25
		1000	0.39	125	2.37	41	0.14	63	0.46	-44
		1500	0.55	104	1.73	15	0.21	51	0.34	-72

Table 2. MPS901 Common Emitter S-Parameters, $V_{CE} = 5.0$ V

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
10	5.0	100	0.79	-33	9.36	144	0.03	68	0.88	-15
		200	0.63	-58	7.97	124	0.04	58	0.74	-22
		500	0.28	-117	4.87	86	0.07	57	0.60	-31
		1000	0.23	153	2.80	53	0.13	56	0.50	-46
		1500	0.38	116	2.09	26	0.19	48	0.38	-69
	10	100	0.60	-48	14.87	132	0.02	66	0.79	-18
		200	0.39	-79	11.06	110	0.03	63	0.65	-21
		500	0.16	-135	5.38	79	0.07	64	0.56	-28
		1000	0.20	138	2.97	50	0.13	59	0.47	-44
		1500	0.37	111	2.21	25	0.20	49	0.36	-66
	15	100	0.46	-61	18.20	124	0.02	66	0.74	-18
		200	0.28	-94	11.94	102	0.03	66	0.62	-19
		500	0.14	-154	5.45	76	0.07	67	0.55	-26
		1000	0.22	131	2.97	48	0.13	61	0.48	-42
		1500	0.38	109	2.21	24	0.20	50	0.36	-64
	20	100	0.37	-72	19.38	119	0.02	67	0.71	-17
		200	0.23	-105	11.97	99	0.03	68	0.61	-18
		500	0.14	-172	5.36	74	0.07	69	0.56	-24
		1000	0.23	128	2.91	47	0.13	62	0.48	-41
		1500	0.40	108	2.16	22	0.20	51	0.37	-64
	25	100	0.32	-86	19.40	115	0.02	68	0.70	-16
		200	0.22	-119	11.67	97	0.03	69	0.61	-16
		500	0.19	-176	5.28	74	0.06	70	0.57	-23
		1000	0.26	127	2.82	46	0.13	63	0.50	-41
		1500	0.43	107	2.09	21	0.19	53	0.40	-63
	30	100	0.29	-103	18.29	112	0.02	68	0.70	-14
		200	0.22	-135	10.86	95	0.03	70	0.62	-15
		500	0.20	165	4.82	72	0.06	72	0.59	-22
		1000	0.31	125	2.63	44	0.12	66	0.53	-41
		1500	0.47	106	1.95	19	0.19	55	0.43	-64

Table 3. MPS901 Common Emitter S-Parameters, $V_{CE} = 10$ V

MRF901

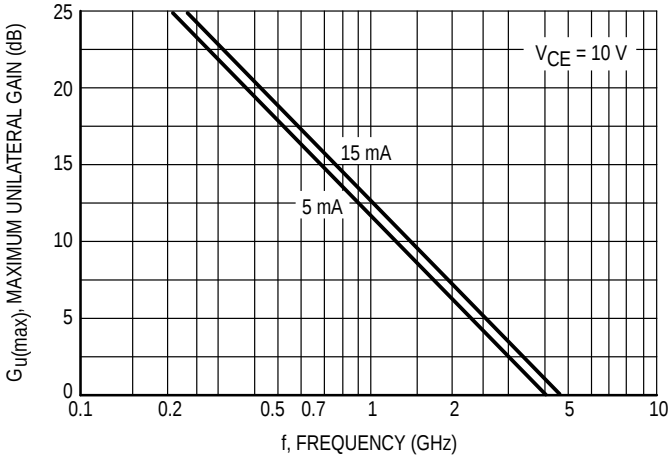


Figure 16. Maximum Unilateral Gain versus Frequency

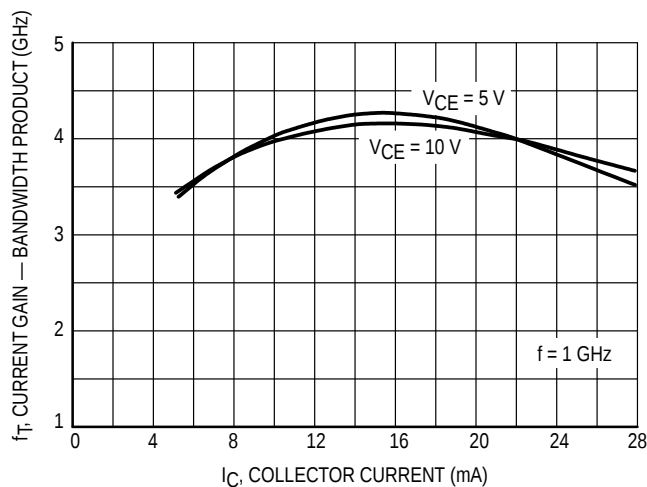


Figure 17. Current Gain — Bandwidth Product versus Collector Current

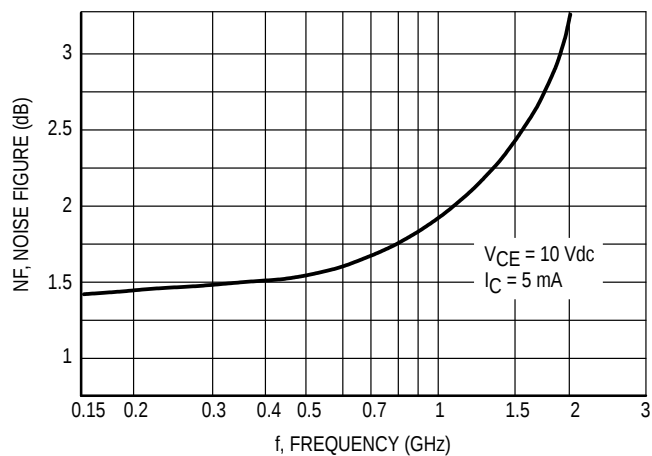


Figure 18. Noise Figure versus Frequency

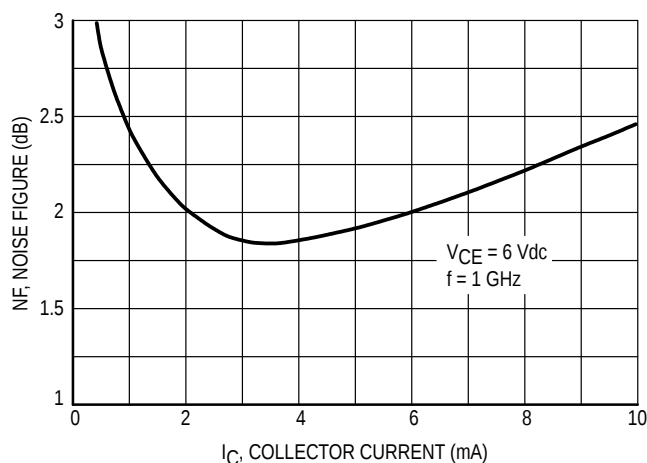


Figure 19. Noise Figure versus Collector Current

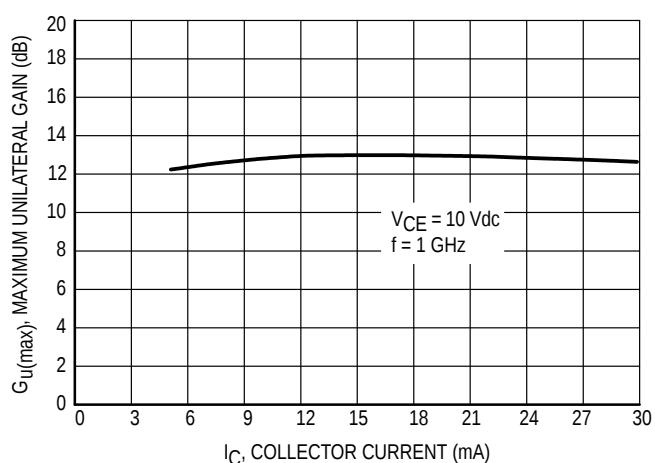


Figure 20. Maximum Unilateral Gain versus Collector Current

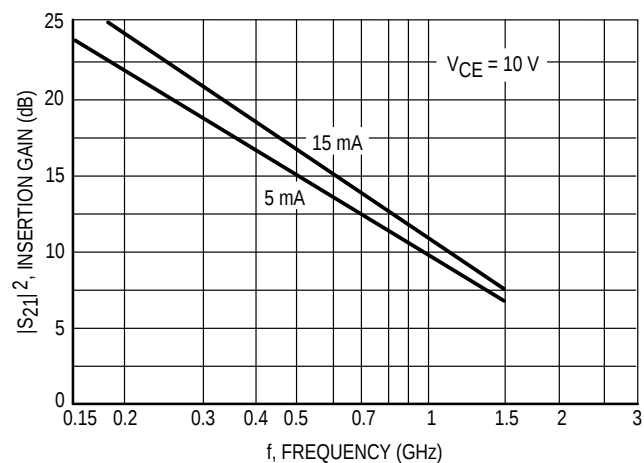


Figure 21. $|S_{21}|^2$ versus Frequency

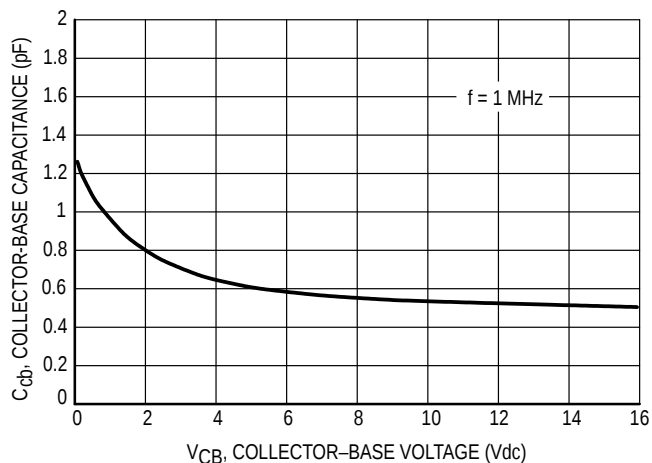


Figure 22. Collector-Base Capacitance versus Collector-Base Voltage

MRF901

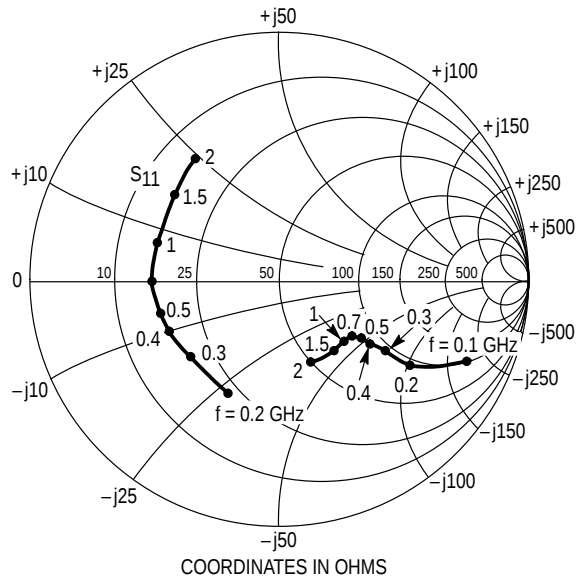


Figure 23. Input and Output Reflection Coefficients versus Frequency
($V_{CE} = 10\text{ V}$, $I_C = 15\text{ mA}$)

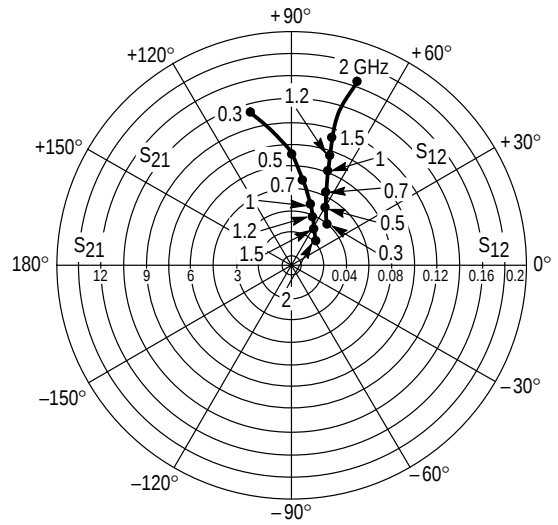


Figure 24. Forward/Reverse Transmission Coefficients versus Frequency
($V_{CE} = 10\text{ V}$, $I_C = 15\text{ mA}$)

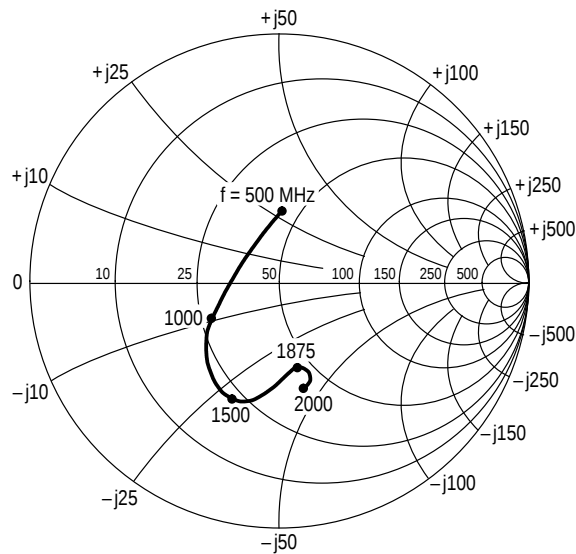


Figure 25. Source Impedance (Γ_{ms}) for Optimum Noise Figure versus Frequency
($V_{CE} = 10\text{ V}$, $I_C = 5.0\text{ mA}$)

MRF901

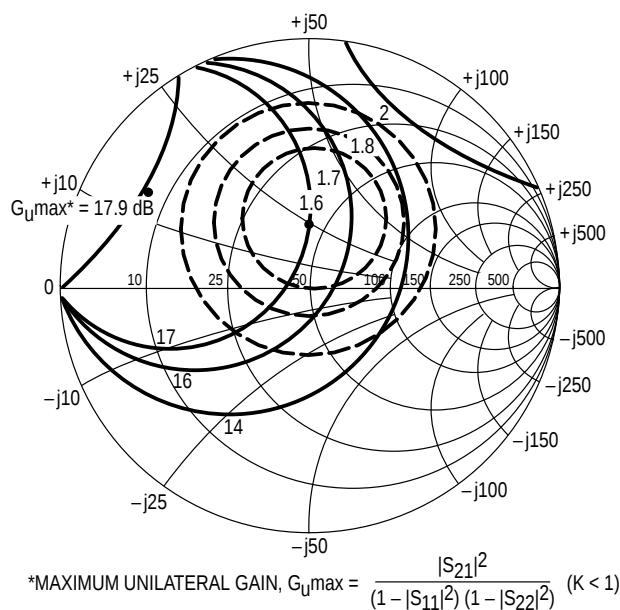


Figure 26. Constant Gain and Noise Figure Contours
($V_{CE} = 10 \text{ Vdc}$, $I_C = 5.0 \text{ mA}$, $f = 500 \text{ MHz}$)

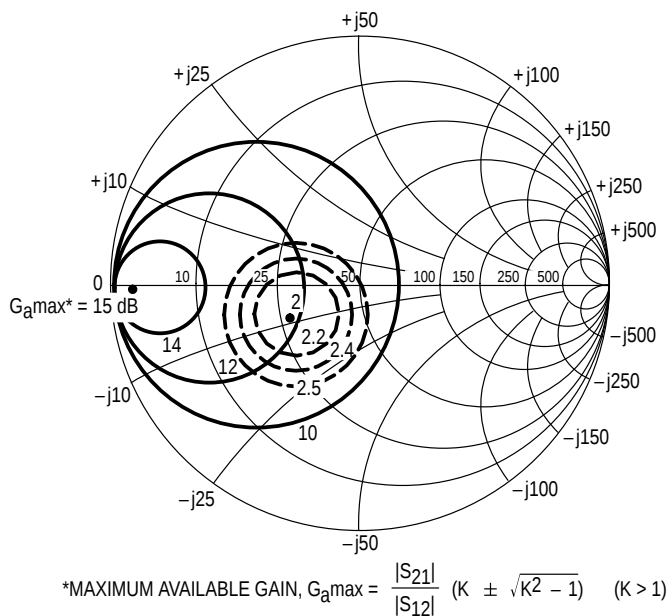


Figure 27. Constant Gain and Noise Figure Contours
($V_{CE} = 10 \text{ Vdc}$, $I_C = 5.0 \text{ mA}$, $f = 1.0 \text{ GHz}$)

MRF901

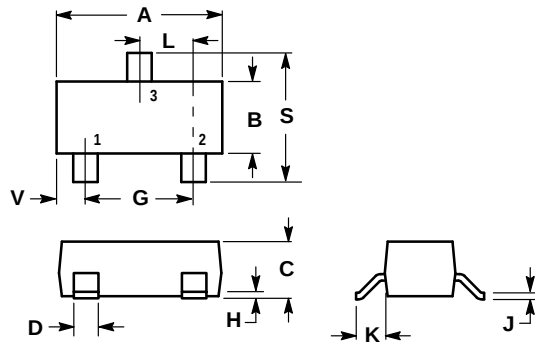
V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
5.0	5.0	100	0.71	-38	11.30	153	0.03	68	0.92	-17
		200	0.62	-75	9.48	133	0.05	55	0.76	-29
		500	0.54	-141	5.40	100	0.07	43	0.48	-44
		1000	0.53	178	2.93	76	0.09	48	0.40	-56
		2000	0.59	130	1.51	48	0.16	62	0.35	-85
	10	100	0.57	-58	16.95	145	0.03	63	0.85	-23
		200	0.51	-103	12.61	123	0.04	53	0.64	-35
		500	0.52	-161	6.24	93	0.06	50	0.38	-45
		1000	0.52	166	3.24	73	0.09	61	0.33	-54
		2000	0.59	125	1.66	47	0.17	67	0.29	-84
	15	100	0.48	-75	20.08	139	0.02	61	0.80	-27
		200	0.47	-121	13.89	117	0.04	53	0.57	-38
		500	0.53	-170	6.44	91	0.05	56	0.34	-44
		1000	0.53	162	3.33	72	0.09	66	0.31	-52
		2000	0.60	123	1.70	46	0.18	68	0.28	-82
	20	100	0.44	-88	21.62	136	0.02	60	0.76	-28
		200	0.47	-132	14.33	114	0.03	54	0.53	-38
		500	0.53	-175	6.45	89	0.05	60	0.32	-41
		1000	0.53	159	3.31	70	0.09	68	0.31	-50
		2000	0.61	122	1.69	45	0.18	70	0.28	-80
	30	100	0.43	-112	21.45	130	0.02	58	0.72	-28
		200	0.50	-148	13.38	109	0.03	57	0.51	-33
		500	0.57	178	5.82	86	0.05	65	0.35	-34
		1000	0.57	156	2.99	68	0.08	73	0.35	-46
		2000	0.65	121	1.50	42	0.18	74	0.33	-78

Table 4. MRF901 Common Emitter S-Parameters, $V_{CE} = 5.0$ V

V_{CE} (Volts)	I_C (mA)	f (MHz)	S_{11}		S_{21}		S_{12}		S_{22}	
			$ S_{11} $	$\angle \phi$	$ S_{21} $	$\angle \phi$	$ S_{12} $	$\angle \phi$	$ S_{22} $	$\angle \phi$
10	5.0	100	0.73	-35	11.32	154	0.03	69	0.93	-14
		200	0.63	-69	9.69	135	0.05	57	0.79	-25
		500	0.53	-135	5.65	101	0.07	43	0.54	-38
		1000	0.51	-177	3.11	77	0.08	50	0.47	-48
		2000	0.57	132	1.58	48	0.14	66	0.41	-75
	10	100	0.59	-52	17.06	147	0.02	64	0.87	-19
		200	0.52	-95	13.06	125	0.04	54	0.69	-30
		500	0.49	-156	6.58	95	0.05	51	0.45	-37
		1000	0.50	170	3.44	74	0.08	62	0.41	-45
		2000	0.57	126	1.75	47	0.16	70	0.36	-72
	15	100	0.51	-66	20.36	141	0.02	63	0.83	-22
		200	0.47	-112	14.48	119	0.03	54	0.63	-31
		500	0.50	-166	6.81	92	0.05	57	0.41	-35
		1000	0.50	164	3.54	72	0.08	67	0.39	-43
		2000	0.58	124	1.78	46	0.16	72	0.35	-70
	20	100	0.47	-78	22.08	138	0.02	61	0.80	-23
		200	0.46	-123	15.07	116	0.03	55	0.60	-30
		500	0.50	-171	6.84	90	0.05	60	0.40	-32
		1000	0.51	162	3.51	71	0.08	69	0.39	-41
		2000	0.59	123	1.77	45	0.17	73	0.35	-68
	30	100	0.44	-98	22.70	133	0.02	59	0.76	-23
		200	0.47	-139	14.47	111	0.03	55	0.57	-27
		500	0.53	-177	6.33	87	0.04	65	0.43	-28
		1000	0.54	158	3.26	69	0.07	74	0.43	-39
		2000	0.62	122	1.61	42	0.16	77	0.39	-68

Table 5. MRF901 Common Emitter S-Parameters, $V_{CE} = 10$ V

PACKAGE DIMENSIONS



NOTES:

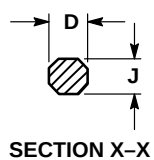
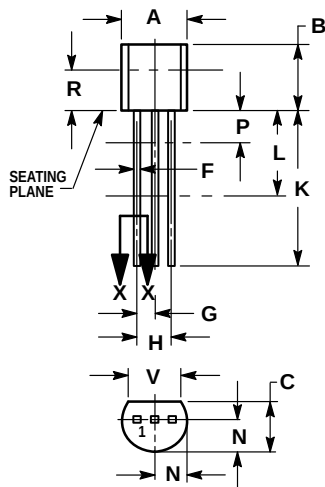
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

**CASE 318-08
ISSUE AE
MMBR901LT1, T3**



NOTES:

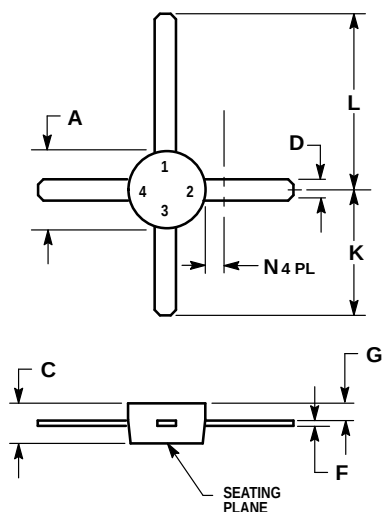
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 2:

- PIN 1. BASE
- EMITTER
- COLLECTOR

**CASE 29-04
ISSUE AD
MPS901**

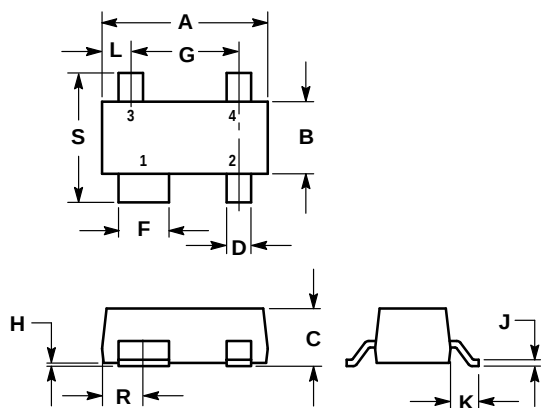


NOTES:
1. DIMENSION D NOT APPLICABLE IN ZONE N.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.44	5.21	0.175	0.205
C	1.90	2.54	0.075	0.100
D	0.84	0.99	0.033	0.039
F	0.20	0.30	0.080	0.012
G	0.76	1.14	0.030	0.045
K	7.24	8.13	0.285	0.320
L	10.54	11.43	0.415	0.450
N	—	1.65	—	0.065

STYLE 2:
PIN 1. COLLECTOR
2. EMITTER
3. BASE
4. EMITTER

CASE 317-01 ISSUE E MRF901



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.80	3.04	0.110	0.120
B	1.20	1.39	0.047	0.055
C	0.84	1.14	0.033	0.045
D	0.39	0.50	0.015	0.020
F	0.79	0.93	0.031	0.037
G	1.78	2.03	0.070	0.080
H	0.013	0.10	0.0005	0.004
J	0.08	0.15	0.003	0.006
K	0.46	0.60	0.018	0.024
L	0.445	0.60	0.0175	0.024
R	0.72	0.83	0.028	0.033
S	2.11	2.48	0.083	0.098

STYLE 1:
PIN 1. COLLECTOR
2. EMITTER
3. EMITTER
4. BASE

CASE 318A-05 ISSUE J MRF9011LT1

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